TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP521-1, TLP521-2, TLP521-4

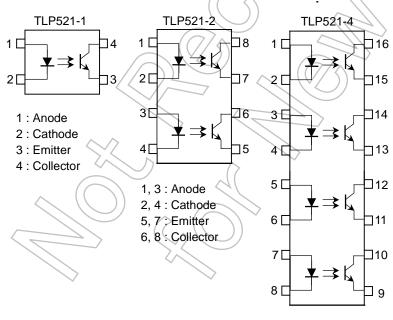
Programmable Controllers AC/DC-Input Module Solid State Relay

The TOSHIBA TLP521-1, -2 and -4 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode.

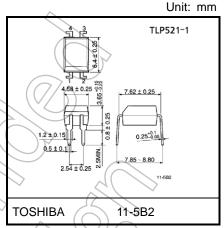
The TLP521-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP521-4 provides four isolated channels in a sixteen plastic DIP package.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min)
  - Rank GB: 100% (min)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1577, file no. E67349
- c-UL recognized: CSA Component Acceptance Service No. 5A
   File No.E67349

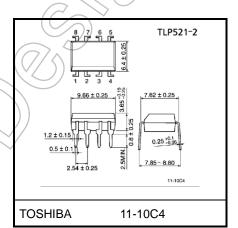
## Pin Configurations (top view)



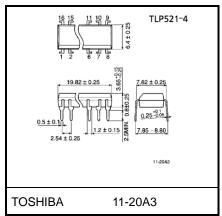
1, 3, 5, 7 : Anode 2, 4, 6, 8 : Cathode 9, 11, 13, 15 : Emitter 10, 12, 14, 16: Collector



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1979-05



#### Absolute Maximum Ratings (Ta = 25°C)

			Ra	ting	
	Characteristic	Symbol	TLP521-1	TLP521-2 TLP521-4	Unit
	Forward current	lF	70	50	mA
	Forward current derating	ΔI <sub>F</sub> /°C	-0.93 (Ta ≥ 50°C)	-0.5 (Ta ≥ 25°C)	mA/°C
	Pulse forward current (100 µs pulse, 100 pps)	lFP	1		A
빌	Reverse voltage	$V_{R}$	!	5	$\rightarrow$
	Diode power dissipation	PD	150	100	(mW
	Diode power dissipation derating	ΔP <sub>D</sub> /°C	-2.0 (Ta ≥ 50°C)	-1.0 (Ta ≥ 25°C)	mW/°C
	Junction temperature	Tj	12	25	°C
	Collector-emitter voltage	VCEO	55		٧
	Emitter-collector voltage	VECO	7		V \
j	Collector current	Ic	50		mA
Detector	Collector power dissipation (1 circuit)	Pc	(100)		mW
	Collector power dissipation derating (1 circuit) (Ta ≥ 25°C)	ΔP <sub>C</sub> /°C		mW/°C	
	Junction temperature	Tj	\(\frac{1}{2}\)	Ç	
Stor	age temperature range	T <sub>stg</sub>	-55 to	ٰC	
Ope	erating temperature range	T <sub>opr</sub>	-55 to	o 100	°C
Lea	d soldering temperature (10 s)	T <sub>sol</sub>	260		°C
Total package power dissipation (1 circuit)		PT	250	150	mW
Total package power dissipation derating (1 circuit) (Ta ≥ 25°C)		ΔΡτ/°C	-2.5	1.5	mW/°C
	ation voltage , 60 s, R.H.≤ 60%) (Note 1)	BVs	25	000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

## **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	Ic	_	1	10	mA
Operating temperature	Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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### **Current transfer ratio**

	Current Transfer Ratio (%) Classi- (IC/IF)		Marking Of				
Туре	fication	IF = 5mA, VCE = 5V, Ta = 25°C		Marking Of Classification			
	(Note 1)	Min	Max				
	Blank	50	600	Blank, Y <sup>*</sup> , YE, G, G <sup>*</sup> , GR, B, BL, GB			
	Rank Y	50	150	YE, Y			
	Rank GR	100	300	GR, G, G <sup>■</sup>			
	Rank BL	200	600	BL, B			
TLP521-1	Rank GB	100	600	GB, GR, G, G <sup>■</sup> , BL, B			
	Rank YH	75	150	Υ•			
	Rank GRL	100	200	G			
	Rank GRH	150	300	G*			
	Rank BLL	200	600	В			
	Blank	50	600	Blank, GR, BL, GB			
TLP521-2	Rank GB	100	600	GB, GR, BL			
1LP521-2	Rank GR	100	300	GR			
	Rank BL	200	600	BL			
TLP521-4	Blank	50	600	Blank, GB			
114521-4	Rank GB	100	600	GB (7/4)			

Note 1: Ex. rank GB: TLP521-1 (GB)

Note: Application type name for certification test, please use standard product type name, i.e. TLP521-1 (GB): TLP521-1, TLP521-2 (GB): TLP521-2





## Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μA
	Capacitance	CT	V = 0 V, f = 1 MHz	7	30		pF
	Collector-emitter breakdown voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> = 0.5 mA	55	_	_	V
jo	Emitter-collector breakdown voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1 mA	X	) /_		V
Detector	Collector dark current ICEO	loro	V <sub>CE</sub> = 24 V	)    }	10	100	nA
De	Collector dark current	ICEO VCE = 24 V, Ta = 85°C	V <sub>CE</sub> = 24 V, Ta = 85°C		2	50	μA
	Capacitance (collector to emitter)	C <sub>CE</sub>	V = 0 V, f = 1 MHz		10		pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Тур.	> Max	Unit
Current transfer ratio	IC/IF	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V Rank GB	50		600	%
Saturated CTR	IC/IF(sat)	I <sub>F</sub> = 1 mA, V <sub>GE</sub> = 0.4 V Rank GB	30	60 —	_	%
Collector-emitter	£	Ic = 2.4 mA, I <sub>F</sub> = 8 mA	) –	_	0.4	
saturation voltage	VCE(sat)	I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA	_	0.2	_	V
-		Rank GB			0.4	

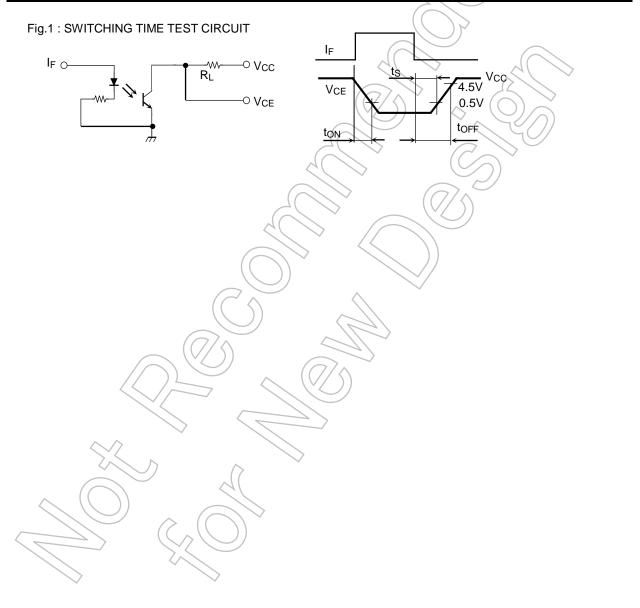
## Isolation Characteristics (Ta = 25°C)

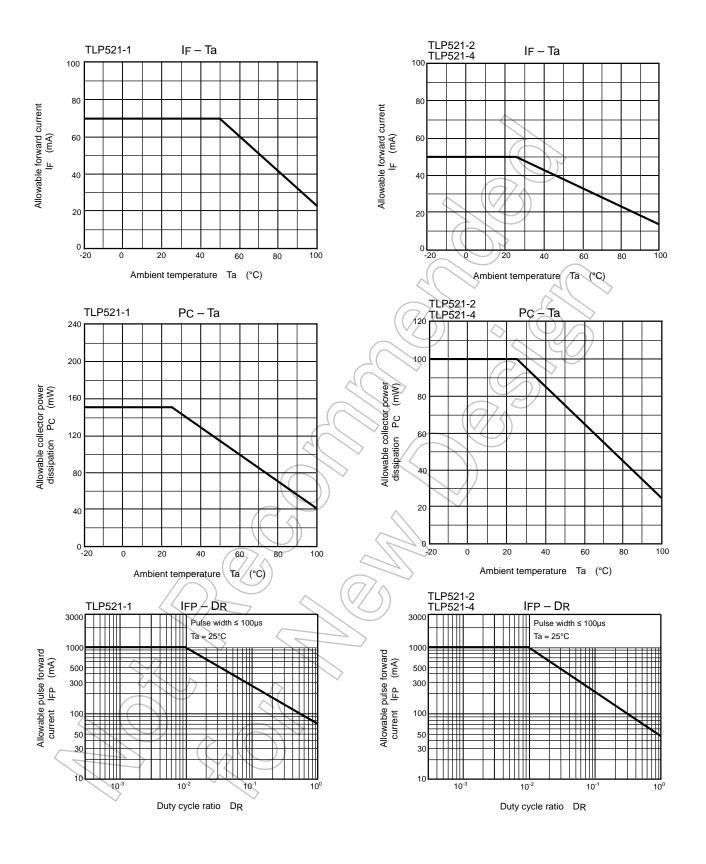
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	$V_S = 0$ $V, f = 1$ MHz		0.8	l	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H.≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>		Ω
		AC, 60 s	2500	_	_	Vrms
Isolation voltage	BVS	AC, 1 s, in oil	_	5000	_	VIIIIS
		DC, 60 s, in oil	_	5000		Vdc

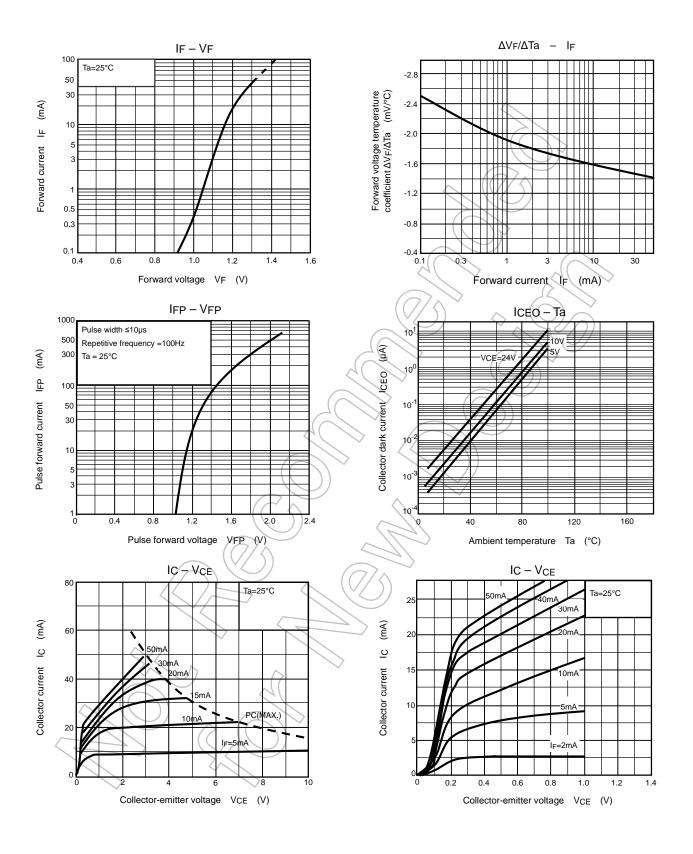


## Switching Characteristics (Ta = 25°C)

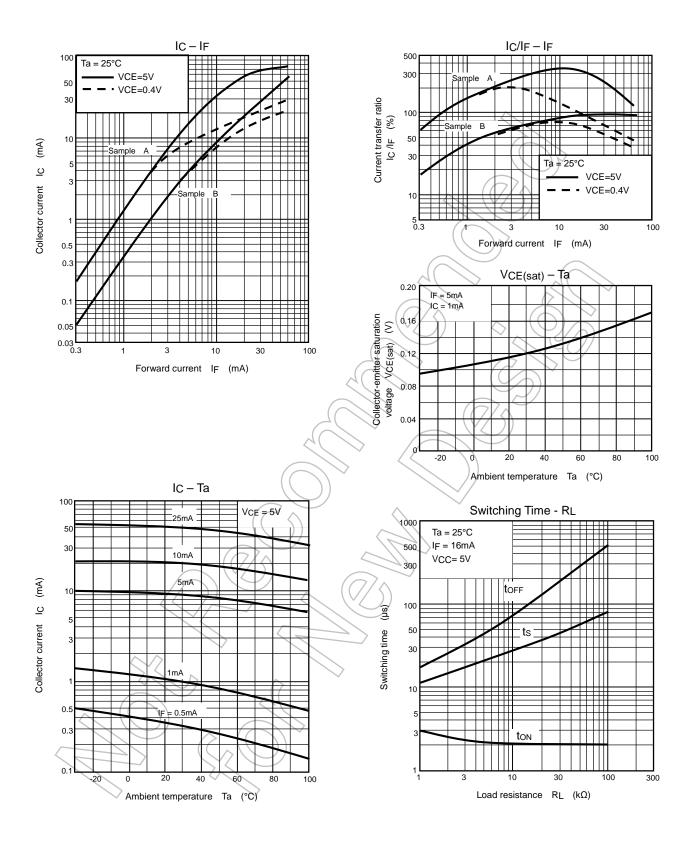
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr		_	2	_	
Fall time	tf	Vcc = 10 V	_	3	_	
Turn-on time	t <sub>on</sub>	IC = 2  mA $RL = 100\Omega$	7	3	_	μs
Turn-off time	toff		(-)	3	_	
Turn-on time	ton		1	) / 2	_	
Storage time	ts	$R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$	77	15	_	μs
Turn-off time	tOFF		$\mathcal{C}$	25	_	







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